



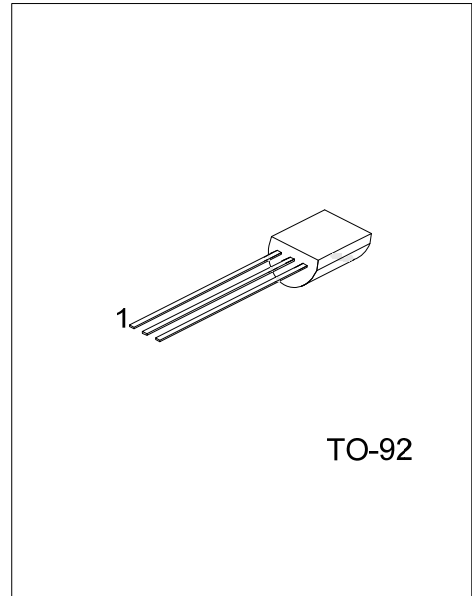
2SB1116/A

PNP SILICON TRANSISTOR

PNP EPITAXIAL SILICON TRANSISTOR

DESCRIPTION

Complement to UTC **2SD1616/A**



ORDERING INFORMATION

Ordering Number			Package	Pin Assignment			Packing
Normal	Lead Free	Halogen Free		1	2	3	
2SB1116-x-T92-B	2SB1116L-x-T92-B	2SB1116G-x-T92-B	TO-92	E	C	B	Tape Box
2SB1116-x-T92-K	2SB1116L-x-T92-K	2SB1116G-x-T92-K	TO-92	E	C	B	Bulk
2SB1116A-x-T92-B	2SB1116AL-x-T92-B	2SB1116AG-x-T92-B	TO-92	E	C	B	Tape Box
2SB1116A-x-T92-K	2SB1116AL-x-T92-K	2SB1116AG-x-T92-K	TO-92	E	C	B	Bulk

2SB1116L-x-T92-B (1)Packing Type (2)Package Type (3)Rank (4)Lead Plating	(1) B: Tape Box, K: Bulk (2) T92: TO-92 (3) x: refer to Classification of h_{FE1} (4) G: Halogen Free, L: Lead Free, Blank: Pb/Sn
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■ ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector to Base Voltage	V_{CBO}	-60	V
		-80	
Collector to Emitter Voltage	V_{CEO}	-50	V
		-60	
Emitter to Base Voltage	V_{EBO}	-6	V
Collector Current	DC	-1	A
	Pulse(Note2)	-2	A
Total Power Dissipation	P_C	0.75	mW
Junction Temperature	T_J	+150	$^\circ\text{C}$
Operating Temperature	T_{OPR}	-20 ~ +85	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 ~ +150	$^\circ\text{C}$

Note: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Pulse width $\leq 10\text{ms}$, Duty cycle $\leq 50\%$

■ ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$, unless otherwise specified.)

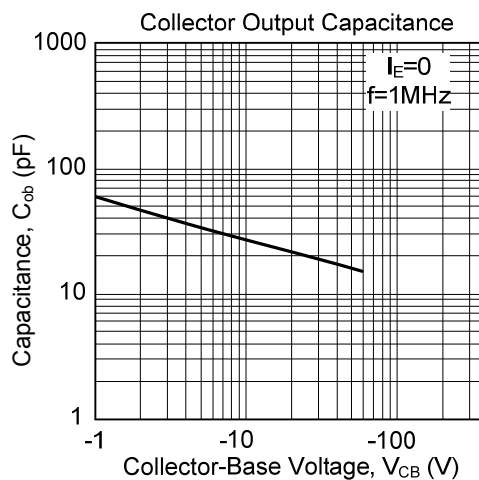
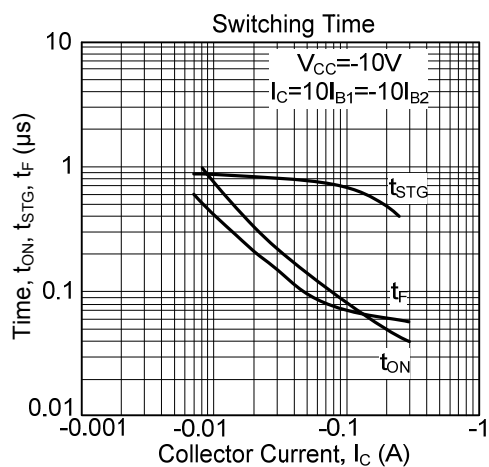
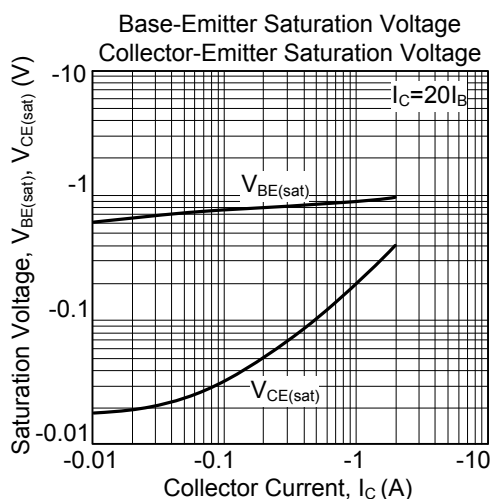
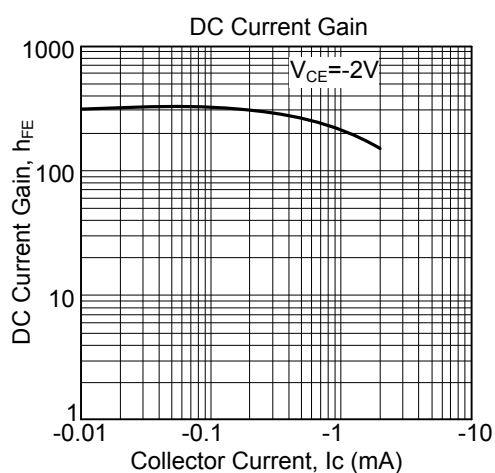
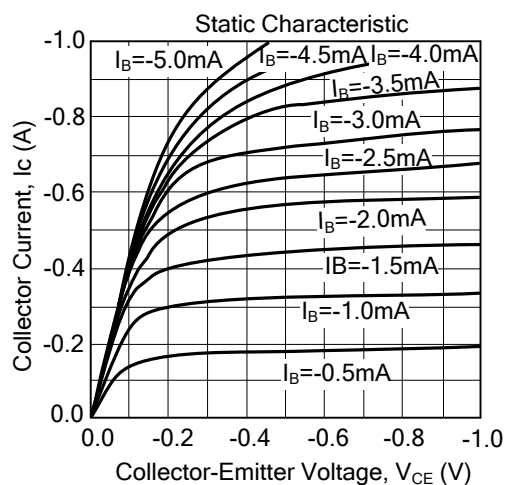
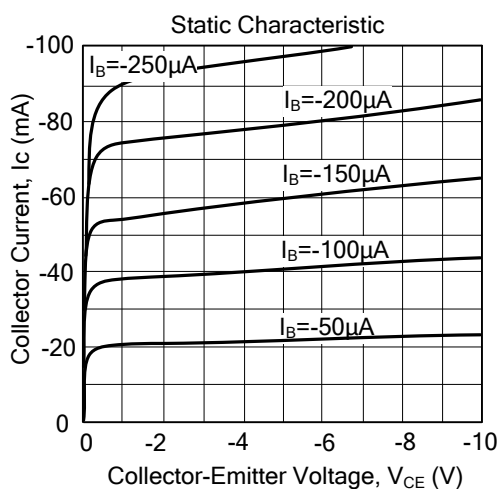
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Saturation Voltage(Note)	$V_{CE(SAT)}$	$I_C=-1\text{A}$, $I_B=-50\text{mA}$		-0.2		V
Base-Emitter Saturation Voltage(Note)	$V_{BE(SAT)}$	$I_C=-1\text{A}$, $I_B=-50\text{mA}$		-0.9	-1.2	V
Base Emitter On Voltage(Note)	$V_{BE(ON)}$	$V_{CE}=-2\text{V}$, $I_C=-50\text{mA}$	-600	-650	-700	mV
Collector Cut-Off Current	I_{CBO}	$V_{CB}=-60\text{V}$, $I_E=0$			-100	nA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=-6\text{V}$, $I_C=0$			-100	nA
DC Current Gain(Note)	h_{FE1}	$V_{CE}=-2\text{V}$, $I_C=-100\text{mA}$	135		600	
			135		400	
	h_{FE2}	$V_{CE}=-2\text{V}$, $I_C=-1\text{A}$	81			
Transition Frequency	f_T	$V_{CE}=-2\text{V}$, $I_C=-100\text{mA}$	70	120		MHz
Output Capacitance	C_{ob}	$V_{CB}=-10\text{V}$, $I_E=0$, $f=1\text{MHz}$		25		pF
Turn On Time	t_{ON}	$V_{CC}=-10\text{V}$, $I_C=-100\text{mA}$ $I_{B1}=-I_{B2}=-10\text{mA}$, $V_{BE(OFF)}=2 \sim 3\text{V}$		0.07		μs
Storage Time	t_{STG}			0.7		μs
Fall Time	t_F			0.07		μs

Note: Pulse Test: Pulse width $\leq 350\mu\text{s}$, Duty cycle $\leq 2\%$

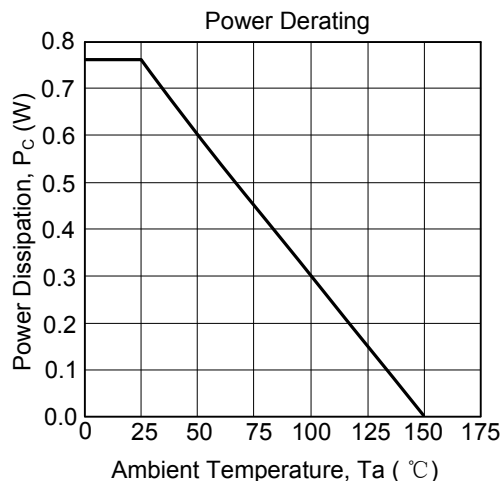
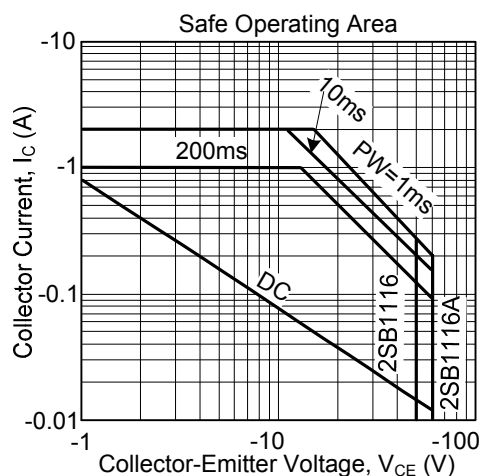
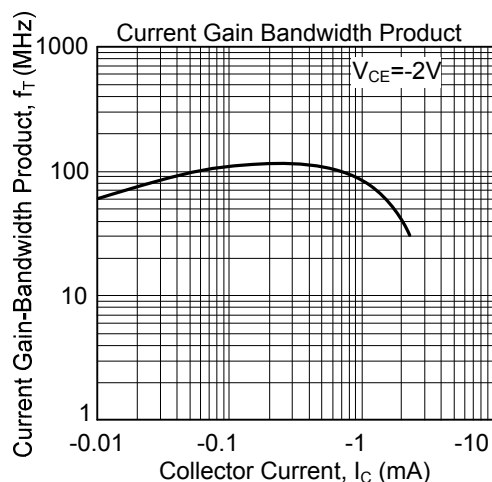
■ CLASSIFICATION OF h_{FE1}

RANK	Y	G	L
h_{FE1}	135 ~ 270	200 ~ 400	300 ~ 600

■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS(Cont.)



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